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## FDD7N60NZ / FDU7N60NZTU N-Channel UniFET<sup>TM</sup> II MOSFET 600 V, 5.5 A, 1.25 $\Omega$

### Features

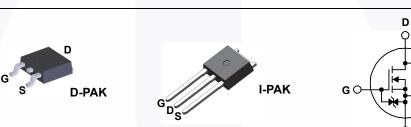
- $R_{DS(on)}$  = 1.05  $\Omega$  (Typ.) @ V<sub>GS</sub> = 10 V, I<sub>D</sub> = 2.75 A
- Low Gate Charge (Typ. 13 nC)
- Low C<sub>rss</sub> (Typ. 7 pF)
- 100% Avalanche Tested
- Improved dv/dt Capability
- · ESD Improved Capability
- RoHS Compliant

## Applications

- Lighting
- Uninterruptible Power Supply

## Description

UniFET<sup>TM</sup> II MOSFET is Fairchild Semiconductor's high voltage MOSFET family based on advanced planar stripe and DMOS technology. This advanced MOSFET family has the smallest onstate resistance among the planar MOSFET, and also provides superior switching performance and higher avalanche energy strength. In addition, internal gate-source ESD diode allows UniFET<sup>TM</sup> II MOSFET to withstand over 2kV HBM surge stress. This device family is suitable for switching power converter applications such as power factor correction (PFC), flat panel display (FPD) TV power, ATX and electronic lamp ballasts.



## MOSFET Maximum Ratings T<sub>C</sub> = 25°C unless otherwise noted.

Symbol		Parameter			
V <sub>DSS</sub>	Drain to Source Voltage		600	V	
V <sub>GSS</sub>	Gate to Source Voltage		±25	V	
ID	Drain Current	- Continuous (T <sub>C</sub> = 25°C)	5.5	Α	
	Drain Current	- Continuous (T <sub>C</sub> = 100°C)	3.3	A	
I <sub>DM</sub>	Drain Current	- Pulsed (Note	1) 22	А	
E <sub>AS</sub>	Single Pulsed Avalanche Energy (Note 2)		2) 347	mJ	
I <sub>AR</sub>	Avalanche Current (Note 1)		1) 5.5	A	
E <sub>AR</sub>	Repetitive Avalanche Energy (Note 1)		1) 12.5	mJ	
dv/dt	Peak Diode Recovery dv/dt (Note 3)		3) 10	V/ns	
P <sub>D</sub>	Dower Dissinction	(T <sub>C</sub> = 25°C)	90	W	
	Power Dissipation	- Derate Above 25°C	0.7	W/ºC	
T <sub>J</sub> , T <sub>STG</sub>	Operating and Storage Temperature Range		-55 to +150	°C	
TL	Maximum Lead Temperature for Soldering, 1/8" from Case for 5 Seconds		ds 300	°C	

## **Thermal Characteristics**

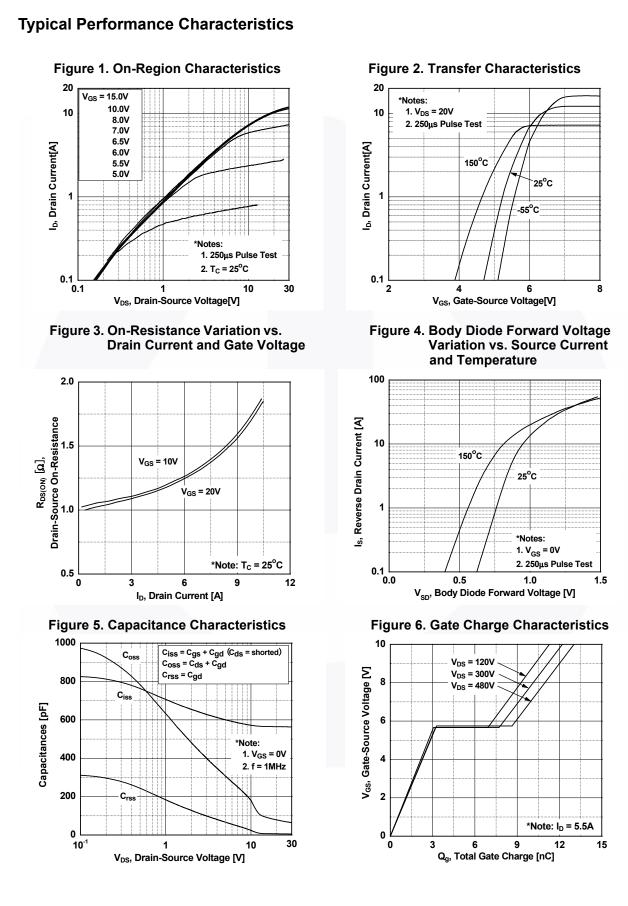
Symbol	Parameter	FDD7N60NZTM/ FDU7N60NZTU	Unit
$R_{\theta JC}$	Thermal Resistance, Junction to Case, Max.	1.4	°C/W
$R_{ extsf{ heta}JA}$	ermal Resistance, Junction to Ambient, Max. 90		0/10

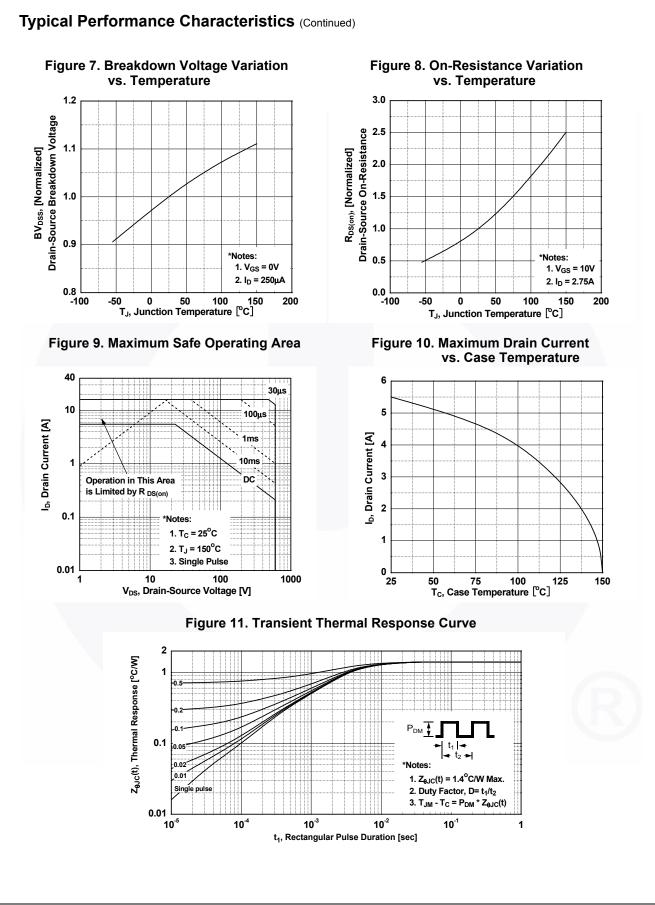
November 2013

Part Number FDD7N60NZTM		Top Mark	Package	Package Packing Method Reel Siz		e T	ape Width	Qu	antity	
		FDD7N60NZ	DPAK	Tape and Reel	330 mm	m 16 mm N/A		2500 units 75 units		
FDU7N60	FDU7N60NZTU FDU7N60NZ		IPAK	Tube	N/A					
Electrica	l Chara	icteristics T <sub>c</sub> = 25°C i	unless other	wise noted.						
Symbol		Parameter		Test Condition	S	Min.	Тур.	Max.	Unit	
- Off Charac	teristics				1				1	
BV <sub>DSS</sub>	Drain to Source Breakdown Voltage		In =	= 250 μΑ, V <sub>GS</sub> = 0 V, T	$= 25^{\circ}C$	600	-	-	V	
ABV <sub>DSS</sub>		wn Voltage Temperature								
$/\Delta T_J$	Coefficier			250 μA, Referenced	to 25°C	-	0.6	-	- V/ºC	
		e Voltage Drain Current		s = 600 V, V <sub>GS</sub> = 0 V		-	-	50	μA	
033				V <sub>DS</sub> = 480 V, T <sub>C</sub> = 125 <sup>o</sup> C		-	-	100	μι	
GSS	Gate to E	Gate to Body Leakage Current		$_{\rm S} = \pm 25 \text{ V}, \text{ V}_{\rm DS} = 0 \text{ V}$		-	-	±10	μA	
On Charac	teristics									
V <sub>GS(th)</sub>	Gate Thr	eshold Voltage	V <sub>GS</sub>	<sub>S</sub> = V <sub>DS</sub> , I <sub>D</sub> = 250 μA		3.0	-	5.0	V	
R <sub>DS(on)</sub>	Static Dra	ain to Source On Resistance	e V <sub>GS</sub>	<sub>S</sub> = 10 V, I <sub>D</sub> = 2.75 A		-	1.05	1.25	Ω	
9 <sub>FS</sub>	Forward	Transconductance	V <sub>DS</sub>	<sub>S</sub> = 20 V, I <sub>D</sub> = 2.75 A		-	7.3	-	S	
Dynamic C	haracte	ristics								
C <sub>iss</sub>	Input Cap	pacitance			-	550	730	pF		
C <sub>oss</sub>	Output C	apacitance		V <sub>DS</sub> = 25 V, V <sub>GS</sub> = 0 V, f = 1 MHz		-	70	90	pF	
C <sub>rss</sub>	Reverse	Transfer Capacitance	1 -		-	-	7	10	pF	
Q <sub>g(tot)</sub>	Total Gat	e Charge at 10V	Vpc	<sub>s</sub> = 400 V, I <sub>D</sub> = 5.5 A,		-	13	17	nC	
Q <sub>gs</sub>	Gate to S	Source Gate Charge		$V_{GS} = 10 V$ (Note 4)		-	3	-	nC	
Q <sub>gd</sub>	Gate to D	Drain "Miller" Charge				-	5.6	-	nC	
Switching	Characte	eristics								
t <sub>d(on)</sub>		Delay Time				-	17.5	45	ns	
r		Rise Time	VDD	<sub>o</sub> = 250 V, I <sub>D</sub> = 5.5 A,	_	-	30	70	ns	
t <sub>d(off)</sub>		Delay Time		$_{\rm S}$ = 10 V, ${\rm R}_{\rm G}$ = 25 $\Omega$	_	-	40	90	ns	
t <sub>f</sub>	Turn-Off	,			(Note 4)	-	25	60	ns	
	rce Diod	e Characteristics					11			
I <sub>s</sub>	-	Continuous Drain to Source	e Diode For	ward Current		-	-	5.5	A	
I <sub>SM</sub>	Maximum Pulsed Drain to Source Diode F					-	-	22	Α	
V <sub>SD</sub>	Drain to Source Diode Forward Voltage		ge V <sub>G</sub> s	$V_{GS} = 0 V, I_{SD} = 5.5 A$		-	-	1.4	V	
	Reverse I	Recovery Time	$V_{GS} = 0 V, I_{SD} = 5.5 A,$ dI <sub>F</sub> /dt = 100 A/µs		-	250		ns		
t <sub>rr</sub>		Recovery Charge			-	1.4	-	μC		

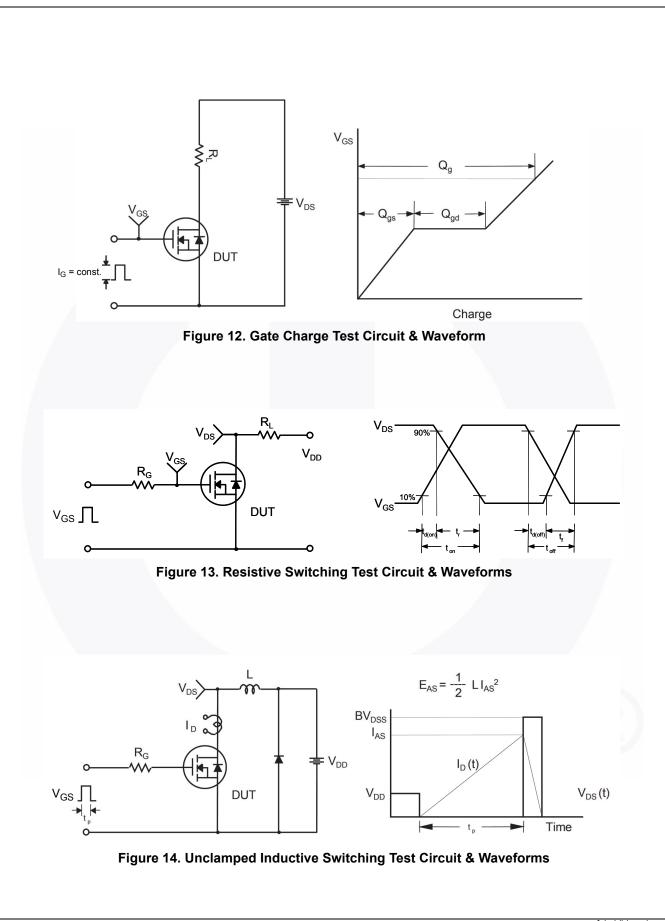
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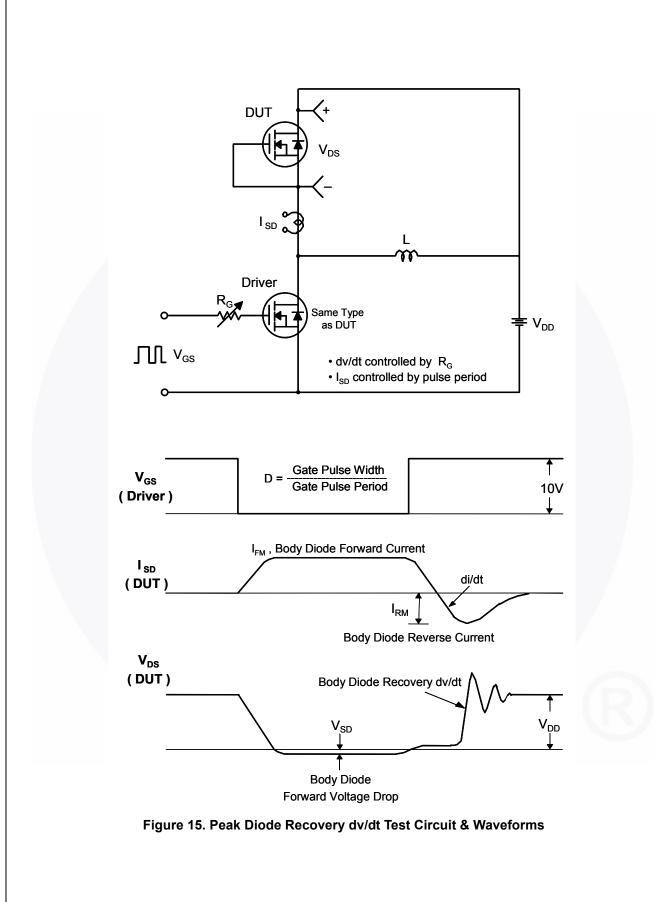


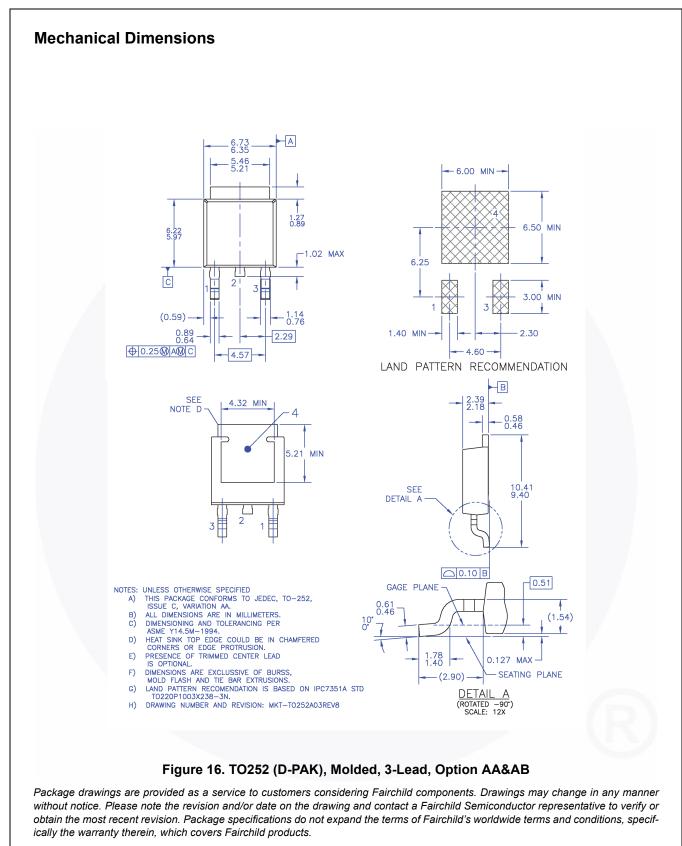




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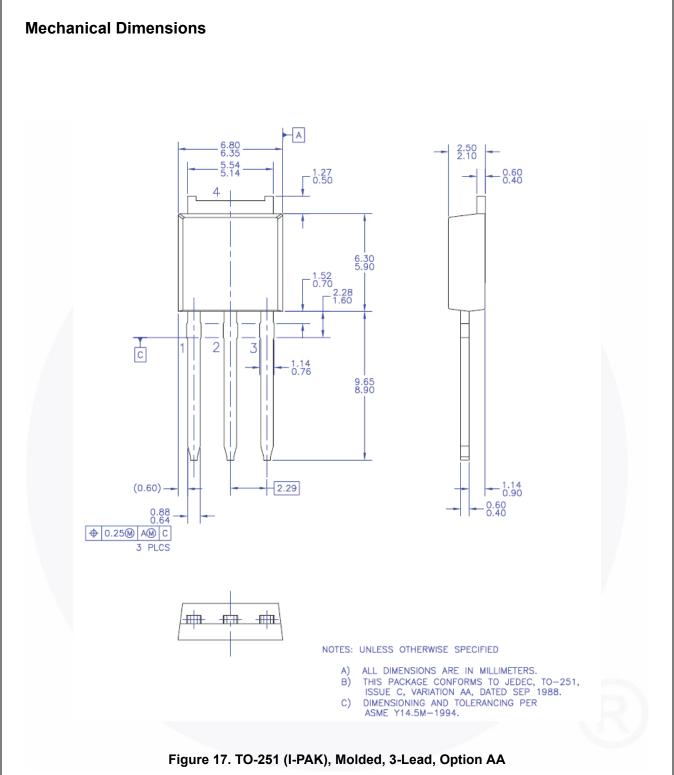




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FDD7N60NZ / FDU7N60NZTU — N-Channel UniFET<sup>TM</sup> II MOSFET



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